

**IN THE SPECIFICATION:**

Please **AMEND** the specification as follows (Exhibit II is a marked up version of the amended Specification):

✓  
Page 5, Paragraph beginning at line 17:

R1 Fig. 2a is a plan view showing a multi-domain liquid crystal display device according to the first embodiment of the present invention;

✓  
Page 5, Paragraph beginning at line 23:

R2 Fig. 3a is a plan view showing a multi-domain liquid crystal display device according to the second embodiment of the present invention;

✓  
Page 6, Paragraph beginning at line 5:

R3 Fig. 4a is a plan view showing a multi-domain liquid crystal display device according to the third embodiment of the present invention;

✓  
Page 6, Paragraph beginning at line 11:

R4 Fig. 5a is a plan view showing a multi-domain liquid crystal display device according to the fourth embodiment of the present invention;

✓  
Page 6, Paragraph beginning at line 17:

R5 Fig. 6a is a plan view showing a multi-domain liquid crystal display device according to the fifth embodiment of the present invention;

Page 6, Paragraph beginning at line 23:

A4 Figs. 7a to 7e are plan views showing a multi-domain liquid crystal display device according to the sixth embodiment of the present invention;

Page 7, Paragraph beginning at line 1:

A7 Figs. 8a to 8e are plan views showing a multi-domain liquid crystal display device according to the seventh embodiment of the present invention;

Page 7, Paragraph beginning at line 4:

A8 Figs. 9a to 9e are plan views showing a multi-domain liquid crystal display device according to the eighth embodiment of the present invention;

Page 7, Paragraph beginning at line 7:

A9 Figs. 10a to 10e are plan views showing a multi-domain liquid crystal display device according to the ninth embodiment of the present invention; and

Page 7, Paragraph beginning at line 10:

A10 Figs. 11a to 11e are plan views showing a multi-domain liquid crystal display device according to the tenth embodiment of the present invention;

Page 7, Paragraph beginning at line 23:

A11 The data lines 3 and gate lines 1 are formed on the first substrate 21 lengthwise and crosswise to divide the first substrate into a plurality of pixel regions. The common auxiliary

Q11  
cont. electrode 15 is formed on a layer equal to the gate lines to distort electric field. The thin film transistor is formed in each pixel region on the first substrate and includes a gate electrode 11, a gate insulating film 35, a semiconductor layer 5, an ohmic contact layer, and source and drain electrodes 7 and 9. The passivation film 37 is formed on an entire surface of the first substrate 31. The pixel electrode 13 is formed on the passivation film 37 to be connected with the drain electrode 9.

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Page 8, Paragraph beginning at line 22:

Q12 To fabricate the aforementioned multi-domain liquid crystal display device, the thin film transistor consisting of the gate electrode 11, the gate insulating film 35, the semiconductor layer 5, the ohmic contact layer and the source and drain electrodes 7 and 9 is formed in each pixel region of the first substrate. At this time, the plurality of gate lines 1 and data lines 3 are formed to divide the first substrate into a plurality of pixel regions.

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Page 9, Paragraph beginning at line 5:

Q13 The gate electrode 11 and gate lines 1 are formed in such a manner that metals such as Al, Mo, Cr, Ta, Al alloy or their alloys are layered by sputtering and patterned. At the same time, the common auxiliary electrode 15 is formed to surround the pixel region. Then, the gate insulating film 35 is formed in such a manner that SiNx or SiOx is deposited on the common auxiliary electrode 15 by plasma enhancement chemical vapor deposition (PECVD) method and patterned. Subsequently, the semiconductor layer 5 and the ohmic contact layer are formed in such a manner that a-Si and n+ a-Si are deposited by PECVD method and patterned. Furthermore, the gate insulating film 35, a-Si and n+ a-Si may successively be deposited and patterned. Metals such as Al, Mo, Cr, Ta, Al alloy or their alloys are layered

Q13 cont. by sputtering and patterned so that the data lines 3 and the source and drain electrodes 7 and 9 are formed.

Page 13, Paragraph beginning at line 12:

Q14 Furthermore, in Figs. 3b and 3d, the passivation film 37 is formed of a material such as SiNx or SiOx. In Figs. 3c and 3e, the passivation film is formed of BCB, acrylic resin or polyimide.

Page 15, Paragraph beginning at line 6:

Q15 Furthermore, in Figs. 5b and 5d, the passivation film 37 is formed of a material such as SiNx or SiOx. In Figs. 5c and 5e, the passivation film 37 is formed of BCB, acrylic resin or polyimide.

Page 16, Paragraph beginning at line 4:

Q14 Furthermore, in Figs. 6b and 6d, the passivation film 37 is formed of a material such as SiNx or SiOx. In Figs. 6c and 6e, the passivation film 37 is formed of BCB, acrylic resin or polyimide.

Page 16, Paragraph beginning at line 17:

Q17 Figs. 7, 8, 9, 10 and 11 show plan views of a multi-domain liquid crystal display device according to the sixth to tenth embodiments of the present invention.